

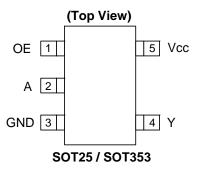
Description

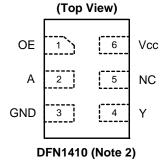
The 74LVCE1G126 is a single non-inverting buffer/bus driver with a 3-state output. The output enters a high impedance state when a LOW-level is applied to the output enable (OE) pin. The device is designed for operation with a power supply range of 1.4V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF}. The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

Features

- Extended Supply Voltage Range from 1.4 to 5.5V
- Switching speed characterized for operation at 1.5V
- Offers 30% speed improvement over LVC at 1.8V.
- ± 24mA Output Drive at 3.3V
- CMOS low power consumption
- IOFF Supports Partial-Power-Down Mode Operation
- Inputs accept up to 5.5V
- ESD Protection Tested per JESD 22
 Exceeds 200-V Machine Model (A115-A)
 Exceeds 2000-V Human Body Model (A114-A)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- · Range of Package Options
- · Direct Interface with TTL Levels
- SOT25, SOT353 and DFN1410: Assembled with "Green" Molding Compound (no Br, Sb)
- Lead Free Finish/ RoHS Compliant (Note 1)

Pin Assignments





Applications

- Voltage Level Shifting
- · Bus Driver / Repeater
- Power Down Signal Isolation
- · General Purpose Logic
- Wide array of products such as.
 - o PCs, networking, notebooks, netbooks, PDAs
 - Computer peripherals, hard drives, CD/DVD ROM
 - TV, DVD, DVR, set top box
 - Cell Phones, Personal Navigation / GPS
 - o MP3 players ,Cameras, Video Recorders

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead_free.html.

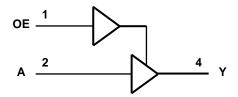
2. Pin 2 and pin 5 of the DFN1410 package are internally connected.



Pin Descriptions

Pin Name	Description				
OE	Output Enable (active high)				
А	Data Input				
GND	Ground				
Y	Data Output				
Vcc	Supply Voltage				

Logic Diagram



Function Table

Inp	uts	Output		
OE	OE A			
Н	Н	Н		
Н	L	L		
L	Х	Z		



Absolute Maximum Ratings (Note 3)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD MM	Machine Model ESD Protection	200	٧
V _{CC}	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	٧
Vo	Voltage applied to output in high impedance or I _{OFF} state	-0.5 to 6.5	٧
Vo	Voltage applied to output in high or low state	-0.3 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current V _I <0	-50	mA
I _{OK}	Output Clamp Current	-50	mA
Io	Continuous output current	±50	mA
	Continuous current through Vdd or GND	±100	mA
TJ	Operating Junction Temperature	-40 to 150	°C
T _{STG}	Storage Temperature	-65 to 150	°C

Note: 3. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 4)

Symbol		Parameter	Min	Max	Unit	
.,	On a ratio a Valta sa	Operating	1.4	5.5	V	
V _{cc}	Operating Voltage	Data retention only	1.2		V	
	High Level Input Voltage	V _{CC} = 1.4 V to 1.95 V	0.65 X V _{CC}			
\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \		V _{CC} = 2.3 V to 2.7 V	1.7		V	
V _{IH}	High Level Input voltage	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	2		V	
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	0.7 X V _{CC}			
		V _{CC} = 1.4 V to 1.95 V		0.35 X V _{CC}		
V _{IL}	Low Level Input Voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V	
V IL	Low Level Input Voltage	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		0.8	V	
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		0.3 X V _{CC}		
VI	Input Voltage		0	5.5	V	
Vo	Output Voltage		0	V _{CC}	V	
	, High Level Output	Vcc=1.4 V		-3		
		V _{CC} = 1.65 V		-4		
		$V_{CC} = 2.3 \text{ V}$		-8	mA	
I _{OH}	Current	$V_{CC} = 3 \text{ V}$		-16	ША	
		V _{CC} = 3 V		-24		
		$V_{CC} = 4.5 \text{ V}$		-32		
		Vcc=1.4 V		3		
		V _{CC} = 1.65 V		4		
	Low Level Output	$V_{CC} = 2.3 \text{ V}$		8	mΑ	
I _{OL}	Current	$V_{CC} = 3 \text{ V}$		16		
		V _{CC} = 3 V		24		
		$V_{CC} = 4.5 \text{ V}$		32		
	Land Charles 200	V _{CC} = 1.4 to 3V		20		
Δt/ΔV	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V	
	iale	$V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$		5		
T _A	Operating free-air temperature		-40	85	°С	

Note: 4. Unused inputs should be held at Vcc or Ground.



Electrical Characteristics (All typical values are at Vcc = 3.3V, T_A = 25°C)

Over recommended free-air temperature range (unless otherwise noted)

Symbol	Parameter	Test Conditions	Vcc	Min	Тур.	Max	Unit
		$I_{OH} = -100 \mu A$	1.4 V to 5.5V	V _{CC} - 0.1			
		$I_{OH} = -3mA$	1.4 V	1.05			
		$I_{OH} = -4mA$	1.65 V	1.2			
V_{OH}	High Level Output Voltage	$I_{OH} = -8mA$	2.3V	1.9			V
	Voltage	$I_{OH} = -16mA$	3 V	2.4			
		$I_{OH} = -24mA$	3 V	2.3			
		$I_{OH} = -32mA$	4.5 V	3.8			
		$I_{OL} = 100 \mu A$	1.4 V to 5.5V			0.1	
		$I_{OL} = 3mA$	1.4V			.4	
	1 - 1 - 10 (- 1	$I_{OL} = 4mA$	1.65 V			0.45	
V_{OL}	Low Level Output Voltage	$I_{OL} = 8mA$	2.3V			0.3	V
	venage	$I_{OL} = 16mA$	3 V			0.4	
		$I_{OL} = 24mA$	3 V			0.55	
		$I_{OL} = 32mA$	4.5			0.55	
I _I	Input Current	$V_1 = 5.5 \text{ V or GND}$	0 to 5.5 V			± 5	μΑ
I _{OFF}	Power Down Leakage Current	V_1 or $V_0 = 5.5V$	0			± 10	μA
l _{oz}	Z State Leakage Current	V _O =0 to 5.5V	3.6V			10	μΑ
I _{cc}	Supply Current	$V_1 = 5.5V$ of GND $I_0=0$	1.4 V to 5.5V			10	μΑ
Δl _{CC}	Additional Supply Current	One input at V _{CC} – 0.6 V Other inputs at V _{CC} or GND	3 V to 5.5V			500	μA
C_{i}	Input Capacitance	$V_i = V_{CC} - \text{ or GND}$	3.3		3.5		pF
	The second Description	SOT25	(Note 5)		204		
θ_{JA}	Thermal Resistance Junction-to-Ambient	SOT353	(Note 5)		371		°C/W
	Canolion to Ambient	DFN1410	(Note 5)		430		
	The survey Decisters in	SOT25	(Note 5)		52		
θ_{JC}	Thermal Resistance Junction-to-Case	SOT353	(Note 5)		143		°C/W
	Junction-to-Case	DFN1410	(Note 5)		190		

Note: 5. Test condition for SOT25, SOT353 and DFN1410: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



Switching Characteristics

Over recommended free-air temperature range, CL = 15pF (see Figure 1)

Parameter	From	то	Vcc = ± 0			: 1.8 V .15V		: 2.5 V).2V		3.3 V 3.3V		= 5 V).5V	Unit
	(Input)	(OUTPUT)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
t _{pd}	Α	Y	1.7	6.9	1.1	4.8	0.4	3.6	0.4	3	0.4	3	ns

Over recommended free-air temperature range, CL = 30 or 50pF as noted (see Figure 2)

Parameter	From	то	Vcc = ± 0			: 1.8 V .15V		: 2.5 V).2V		: 3.3 V).3V		= 5 V).5V	Unit
	(Input)	(OUTPUT)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
t _{pd}	Α	Y	2.6	8	1.8	5.6	0.8	4.4	0.8	3.6	0.9	3.6	ns
t _{en}	ŌE	Υ	2.8	9.4	1.9	6.5	1	5.2	0.9	4.3	0.9	4.3	
t _{dis}	OE	Y	1.6	9.8	1.1	6.8	0.8	4.4	0.8	4.5	0.9	3.7	

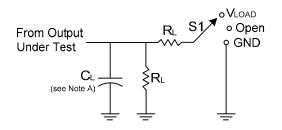
Operating Characteristics

 $T_A = 25$ °C

	Parameter		Test	Vcc = 1.5 V	Vcc = 1.8 V	Vcc = 2.5 V	Vcc = 3.3 V	Vcc = 5 V	Unit
			Conditions	TYP	TYP	TYP	TYP	TYP	
	Power dissipation	Outputs enabled	f = 10 MHz	19	19	19	19	19	pF
C _{pd}	capacitance	Outputs disabled	1 = 10 101112	2	2	2	3	4	рг

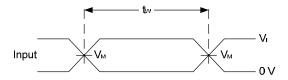


Parameter Measurement Information

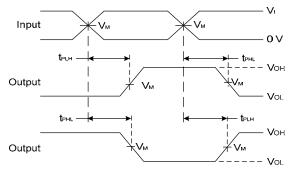


TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	Vload
t _{PHZ} /t _{PZH}	GND

Vcc	In	puts	V	0.	D.	
VCC	Vı	t _r /t _f	· V _M	CL	R_{L}	
1.5V±0.1V	V _{CC}	≤2ns	V _{CC} /2	15pF	1ΜΩ	
1.8V±0.15V	V _{CC}	≤2ns	V _{CC} /2	15pF	1ΜΩ	
2.5V±0.2V	V _{cc}	≤2ns	V _{CC} /2	15pF	1ΜΩ	
3.3V±0.3V	3V	≤2.5ns	1.5V	15pF	1ΜΩ	
5V±0.5V	V _{CC}	≤2.5ns	V _{CC} /2	15pF	1ΜΩ	



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Output
Control

Output
Waveform 1
S1 at V_{LOAD}
(see Note B)

Output
Waveform 2
S1 at GND
(see Note B)

Output

V_M

V

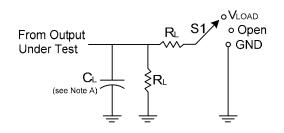
Voltage Waveform Enable and Disable Times
Low and High Level Enabling

- Notes: A. Includes test lead and test apparatus capacitance.
 - B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
 - C. Inputs are measured separately one transition per measurement.
 - D. t_{PLZ} and t_{PHZ} are the same as $t_{dis.}$
 - E. t_{PZL} and t_{PZH} are the same as t_{EN} .
 - F. t_{PLH} and t_{PHL} are the same as t_{PD.}

Figure 1. Load Circuit and Voltage Waveforms

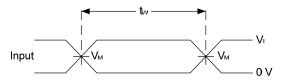


Parameter Measurement Information (Continued)

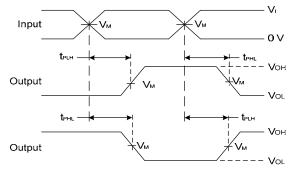


TEST	S1
t _{PLH} /t _{PHL}	Open
t_{PLZ}/t_{PZL}	Vload
t _{PHZ} /t _{PZH}	GND

Vcc	Inj	outs	V _M	CL	RL
	Vi	t _r /t _f	- IVI	OL.	
1.5V±0.1V	V _{cc}	≤2ns	V _{CC} /2	30pF	1ΚΩ
1.8V±0.15V	V _{cc}	≤2ns	V _{CC} /2	30pF	1ΚΩ
2.5V±0.2V	V _{cc}	≤2ns	V _{CC} /2	30pF	500Ω
3.3V±0.3V	3V	≤2.5ns	1.5V	50pF	500Ω
5V±0.5V	V _{CC}	≤2.5ns	V _{CC} /2	50pF	500Ω



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Output
Control

Output
Waveform 1
S1 at V_{LOAD}
(see Note B)

Output
Waveform 2
S1 at GND
(see Note B)

V_M

Voltage Waveform Enable and Disable Times Low and High Level Enabling

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLZ} and t_{PHZ} are the same as $t_{dis.}$
- E. t_{PZL} and t_{PZH} are the same as t_{EN0}
- F. t_{PLH} and t_{PHL} are the same as $t_{PD.}$

Figure 2. Load Circuit and Voltage Waveforms



Ordering Information

T4LVCE1G 126 XXX - 7

Logic Device Function Package Packing

74: Logic Prefix 126: 3-State Buffer W5: SOT25 7: Tape & Reel

LVCE : 1.4 to 5.5V OE-High SE : SOT353
Family FZ4 : DFN1410

1G: One gate

	Dovice	Package	Packaging	7" Tape and Reel	
	Device	Code	(Note 5)	Quantity	Part Number Suffix
Pb ,	74LVCE1G126W5-7	W6	SOT25	3000/Tape & Reel	-7
Pb ,	74LVCE1G126SE-7	SE	SOT353	3000/Tape & Reel	-7
Pb ,	74LVCE1G126FZ4-7	FZ4	DFN1410	5000/Tape & Reel	-7

Note: 6. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.



Marking Information

(1) SOT25 and SOT353

(Top View)

5 4

2

1

XX Y WX

3

XX : Identification code Y : Year 0~9

 \underline{W} : Week : A $^{\sim}$ Z : 1 $^{\sim}$ 26 week;

a z : 27 5 2 week; z represents 52 and 53 week

52 and 53 week X : A~Z : Internal code

Part Number	Package	Identification Code
74LVCE1G126W5	SOT25	PZ
74LVCE1G126SE	SOT353	PZ

(2) DFN1410

(Top View)

XX YWX XX: Identification Code

Y: Year : 0~9

W: Week: A~Z: 1~26 week;

a~z: 27~52 week; z represents

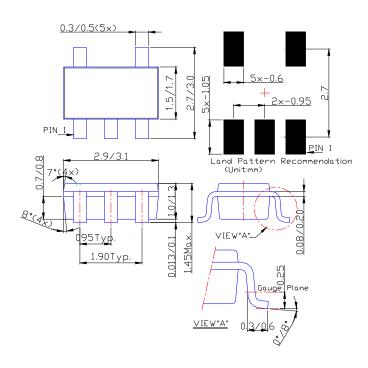
52 and 53 week X: A~Z: Internal code

Part Number	Package	Identification Code
74LVCE1G126FZ4	DFN1410	PZ

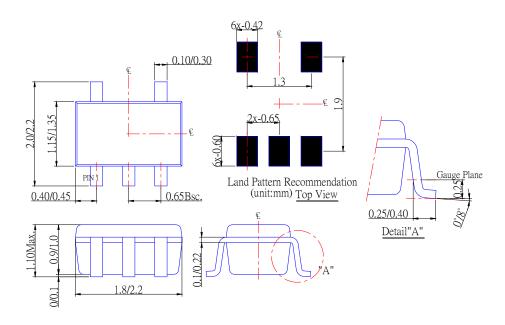


Package Outline Dimensions (All Dimensions in mm)

(1) Package Type: SOT25



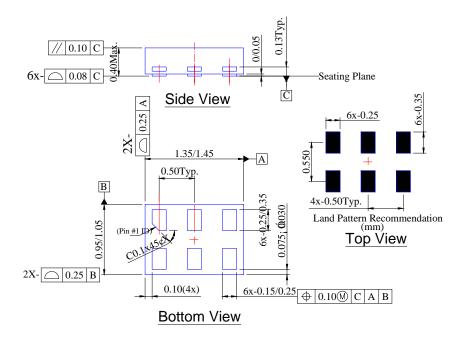
(2) Package Type: SOT353





Package Outline Dimensions (All Dimensions in mm)

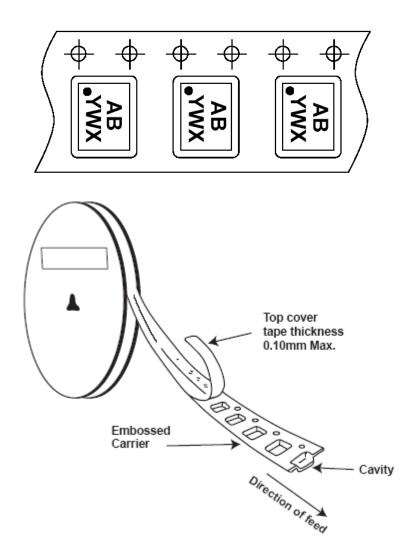
(3) Package Type: DFN1410





Taping Orientation (Note 7)

For DFN1410



Note: 7. The taping orientation of the other package type can be found on our website at http://www.diodes.com/datasheets/ap02007.pdf



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